

# MOS FIELD EFFECT TRANSISTOR $\mu PA1707$

### SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

#### DESCRIPTION

The  $\mu$ PA1707 is N-Channel MOS Field Effect Transistor designed for DC/DC converters and power management applications of notebook computers.

#### FEATURES

Low on-resistance

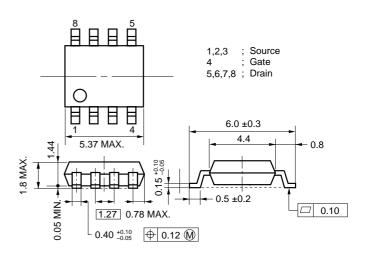
 $\begin{array}{l} R_{DS(on)1} = 10.0 \mbox{ m}\Omega \mbox{ TYP.} \ (V_{GS} = 10 \mbox{ V}, \mbox{ Id} = 5.0 \mbox{ A}) \\ R_{DS(on)2} = 12.5 \mbox{ m}\Omega \mbox{ TYP.} \ (V_{GS} = 4.5 \mbox{ V}, \mbox{ Id} = 5.0 \mbox{ A}) \end{array}$ 

- $R_{DS(on)3} = 14.0 \text{ m}\Omega \text{ TYP.}$  (VGs = 4.0 V, ID = 5.0 A)
- Low Ciss: Ciss = 1400 pF TYP.
- Built-in G-S protection diode
- Small and surface mount package (Power SOP8)

#### **ORDERING INFORMATION**

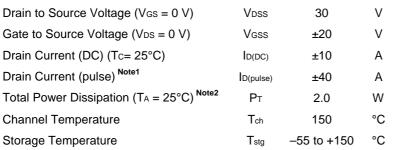
PART NUMBER	PACKAGE
μΡΑ1707G	Power SOP8

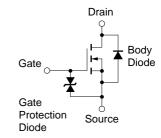
#### PACKAGE DRAWING (Unit : mm)



#### ABSOLUTE MAXIMUM RATINGS (TA = 25°C, All terminals are connected.)

#### EQUIVALENT CIRCUIT





**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%

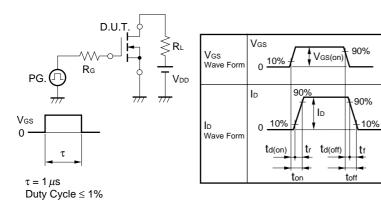
- 2. Mounted on ceramic substrate of 1200 mm<sup>2</sup> x 1.7 mm
- **Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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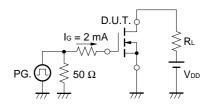
ELECTRICAL CHARACTERISTICS (TA = 25°C, All terminals are connected.)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	Vds = 30 V, Vgs = 0 V			10	μA
Gate Leakage Current	lgss	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μA
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	1.5	2.0	2.5	V
Forward Transfer Admittance	y <sub>fs</sub>	Vds = 10 V, Id = 5.0 A	5.0	13		S
Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, Id = 5.0 A		10.0	13.5	mΩ
	RDS(on)2	Vgs = 4.5 V, Id = 5.0 A		12.5	18	mΩ
	RDS(on)3	Vgs = 4.0 V, Id = 5.0 A		14.0	21	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = 10 V		1400		pF
Output Capacitance	Coss	V <sub>GS</sub> = 0 V		450		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		180		pF
Turn-on Delay Time	td(on)	ID = 5.0 A		20		ns
Rise Time	tr	VGS(on) = 10 V		185		ns
Turn-off Delay Time	td(off)	V <sub>DD</sub> = 15 V		65		ns
Fall Time	tr	R <sub>G</sub> = 10 Ω		40		ns
Total Gate Charge	QG	ID = 10 A		26		nC
Gate to Source Charge	Q <sub>GS</sub>	V <sub>DD</sub> = 24 V		4.2		nC
Gate to Drain Charge	Qgd	V <sub>GS</sub> = 10 V		6.5		nC
Body Diode Forward Voltage	VF(S-D)	IF = 10 A, VGs = 0 V		0.8		V
Reverse Recovery Time	trr	IF = 10 A, VGS = 0 V		30		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ µs		25		nC

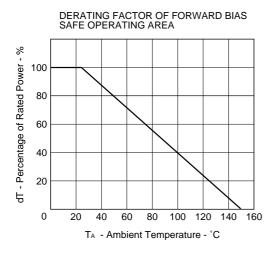
#### **TEST CIRCUIT 1 SWITCHING TIME**

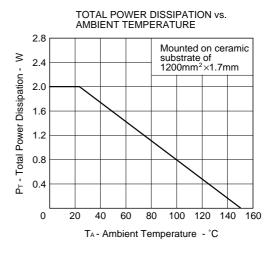


#### TEST CIRCUIT 2 GATE CHARGE

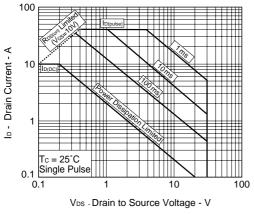


#### TYPICAL CHARACTERISTICS ( $T_A = 25^{\circ}C$ )

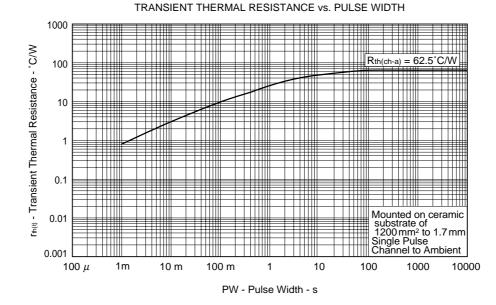




FORWARD BIAS SAFE OPERATING AREA

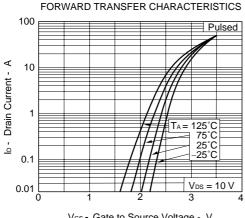


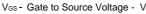
#### **Remark** Mounted on ceramicsubstrate of $1200 \text{ mm}^2 \times 1.7 \text{ mm}$

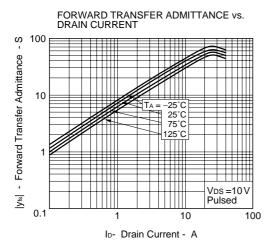


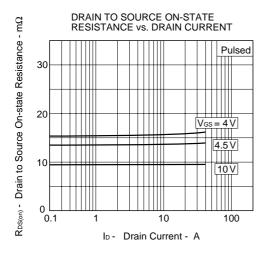
Data Sheet G13084EJ2V0DS

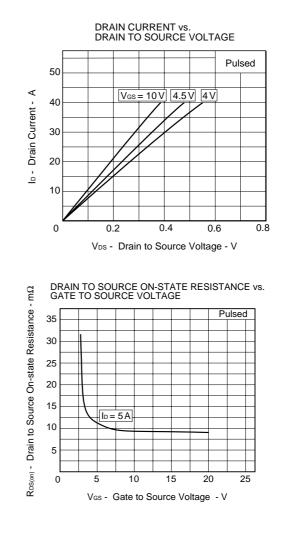




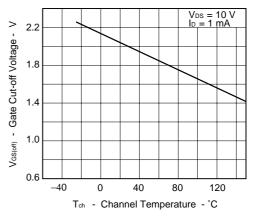






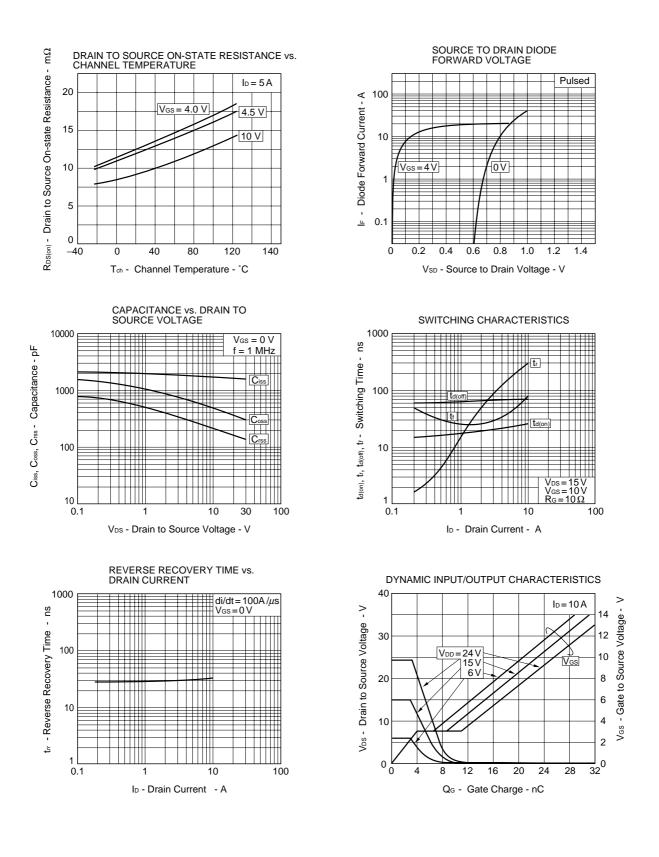


GATE CUT-OFF VOLTAGE vs.CHANNEL TEMPERATURE



Data Sheet G13084EJ2V0DS

NEC



Data Sheet G13084EJ2V0DS

[MEMO]

## NEC

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